

DATASHEET

Opto Interrupter ITR8104



Features

- · Fast response time
- · High analytic
- Cut-off visible wavelength λp=940nm
- · High sensitivity
- Pb free
- This product itself will remain within RoHS compliant version

Description

- The **ITR8104** consist of an infrared emitting diode and an NPN silicon phototransistor, encased side-by-side on converging optical axis in a black thermoplastic housing,
- The phototransistor receives radiation from the IR only .This is the normal situation.
- But when an object is in between , phototransistor could not receives the radiation.

Applications

- Mouse Copier
- Switch Scanner
- · Floppy disk driver
- Non-contact Switching
- For Direct Board



Device Selection Guide

Chip Materials	Lens Color
GaAlAs	Water clear
Silicon	Water clear

Absolute Maximum Ratings (Ta=25℃)

Parameter		Symbol	Ratings	Unit
	Power Dissipation at(or below) 25° Free Air Temperature	Pd	75	mW
	Reverse Voltage	V_R	5	V
	Forward Current	I _F	50	mA
	Peak Forward Current (*1) Pulse width ≤ 100μs, Duty cycle=1%	I _{FP}	1	Α
Output	Collector Power Dissipation	Pd	75	mW
	Collector Current	I _C	20	mA
	Collector-Emitter Voltage	B V _{CEO}	30	V
	Emitter-Collector Voltage	B V _{ECO}	5	V
Operating Temperature		Topr	-40~+85	$^{\circ}\mathbb{C}$
Storage Temperature		Tstg	-40~+85	$^{\circ}\mathbb{C}$
Lead Soldering Temperature (*2) (1/16 inch form body for 5 seconds)		Tsol	260	$^{\circ}$

^(*1) $tw=100 \mu sec.$, T=10 msec. (*2) t=5 Sec.

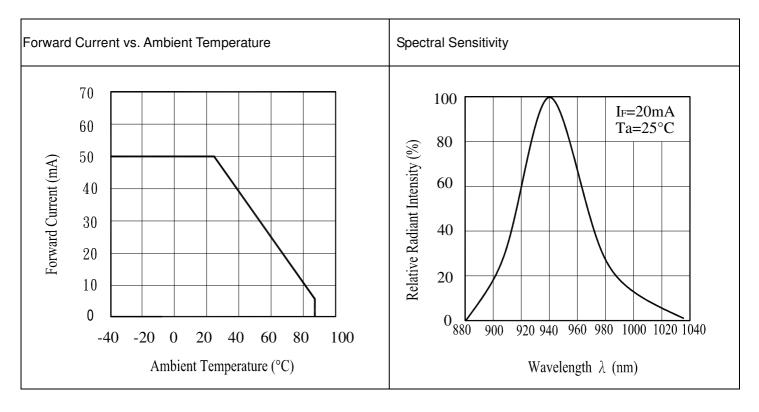


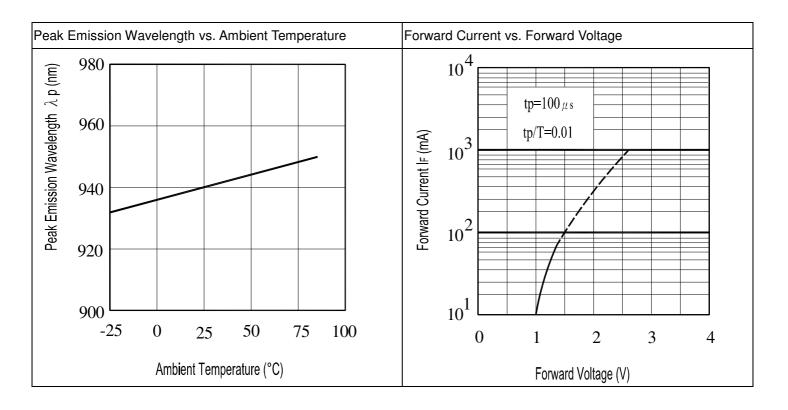
Electro-Optical Characteristics (Ta=25℃)

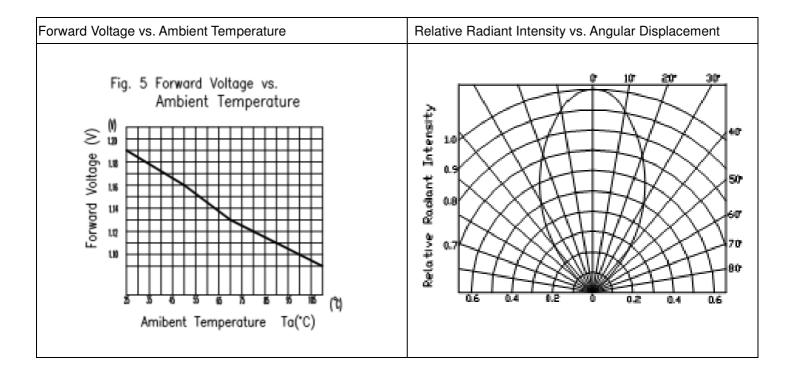
Parameter		Symbol	Min.	Тур.	Max.	Unit	Conditions	
Input	Forward Voltage	V_{F}		1.2	1.6	V	I _F =20mA	
	Reverse Current	I _R			10	μΑ	$V_R=5V$	
	Peak Wavelength	λ_{P}		940		nm	I _F =20mA	
	View Angle	201/2		60		Deg	I _F =20mA	
Output	Dark C urrent	I _{CEO}			100	nA	V _{CE} =20V,Ee=0mW/cm ²	
	C-E Saturation Voltage	V _{CE} (sat)			0.4	V	I _C =2mA ,Ee=1mW/cm²	
Transfer Characteristics	Collect Current	I _C (ON)	0.5			mA	V _{CE} =5V I _F =20mA	
		$I_{C(OFF)}$			20	μΑ	V _{CE} =5V I _F =0mA	
	Rise time	t _r		20		µsec	V _{CE} =5V	
	Fall time	t _f		20		µsec	$I_C=1$ mA $R_L=1$ K $Ω$	



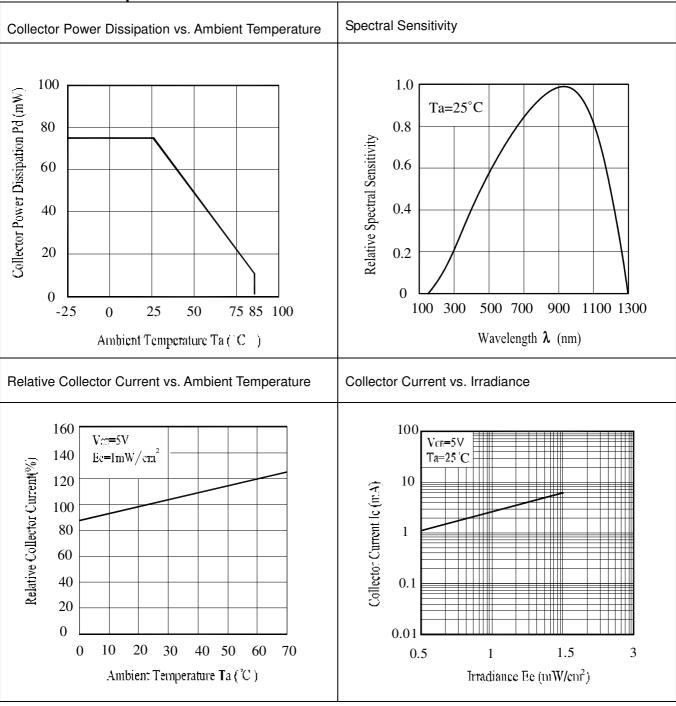
Typical Electrical/Optical/Characteristics Curves for IR

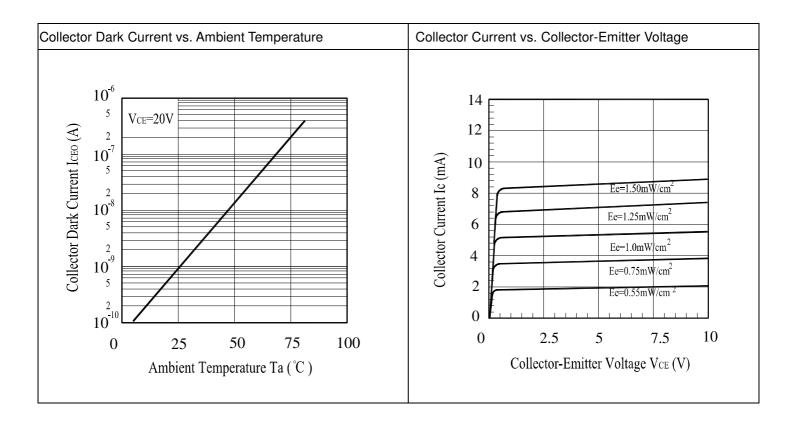






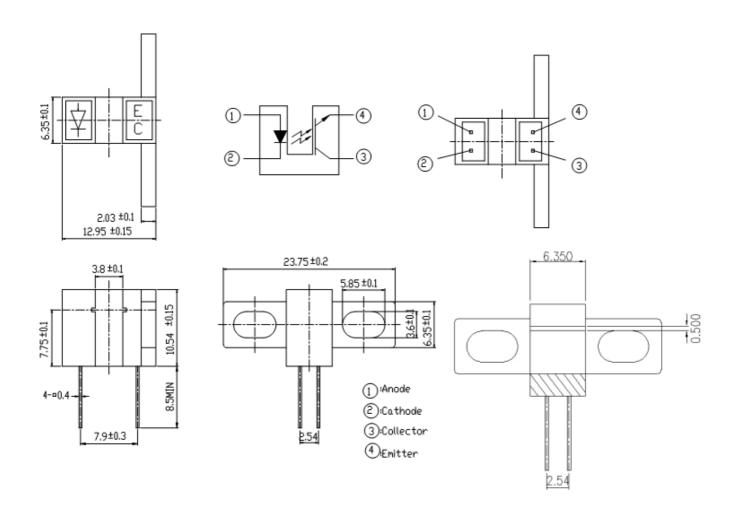
Typical Electrical/Optical/Characteristics Curves for PT







Package Dimension



Note: Tolerances unless dimensions ±0.25mm

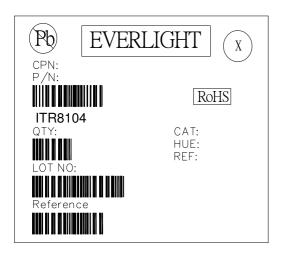


Packing Quantity Specification

1.27PCS/1Tube, 100 Tubes/1Box

2. 4Boxes/1Carton

Label Form Specification



- · CPN: Customer's Product Number
- P/N: Product Number
- QTY: Packing Quantity
- · CAT: Luminous Intensity Rank
- · HUE: Dom. Wavelength Rank
- · REF: Forward Voltage Rank
- · LOT No: Lot Number
- · X: Month
- · Reference: Identify Label Number

Notes

- 1. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
- 2. When using this product, please observe the absolute maximum ratings and the instruction for using outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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